

## MODULATOR

# MX-LN series

## 1550 nm band intensity Modulators

The MX-LN series are lithium niobate ( $\text{LiNbO}_3$ ) intensity modulators designed for optical communications at data rates up to 44 Gb/s.

The X-cut design of these Mach-Zehnder modulators confer them an unmatched stability in a wide range of operational conditions, as well as a zero chirp performance. IXblue proprietary waveguide design offers a low insertion loss combined with a high contrast. The MX-LN series are ideally suited for few kb/s up to 44 Gb/s optical transmission with NRZ, RZ, DPSK, Duo Binary modulation formats and are key device for a large variety of high bandwidth applications.



### FEATURES

- High bandwidth
- X-cut for high stability
- Low drive voltage
- Low insertion loss

### APPLICATIONS

- Digital communications
- General purpose intensity modulation
- Test and measurement

### OPTIONS

- High extinction ratio versions
- 2000 nm, 1300 nm, 1060 nm, 850 nm

### RELATED EQUIPMENTS

- RF amplifiers
- MBC-DG Automatic Bias Controllers
- Modbox-CBand-NRZ
- Modbox-CBand-PAM4
- Modbox-VNA-CBand

### MX-LN-01 Performance Highlights\*

Parameter	Min	Typ	Max	Unit
Operating wavelength	1530	1550	1580	nm
Electro-optical bandwidth	100	400	-	MHz

### MX-LN-05 Performance Highlights\*

Parameter	Min	Typ	Max	Unit
Operating wavelength	1530	1550	1580	nm
Electro-optical bandwidth	3	4	-	GHz

### MX-LN-10 Performance Highlights\*

Parameter	Min	Typ	Max	Unit
Operating wavelength	1530	1550	1625	nm
Electro-optical bandwidth	10	12	-	GHz

### MX-LN-20 Performance Highlights\*

Parameter	Min	Typ	Max	Unit
Operating wavelength	1530	1550	1625	nm
V $\pi$ RF @50 kHz	-	5	-	V

### MX-LN-40 Performance Highlights\*

Parameter	Min	Typ	Max	Unit
Operating wavelength	1530	1550	1625	nm
V $\pi$ RF @50 kHz	-	5	-	V

\*Specifications given at 25 °C, 1550 nm

**IXblue**

**MX-LN-0.1**

## 100 MHz Intensity Modulator

**Electrical Characteristics**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	$S_{21}$	RF electrodes, from 2 GHz	100	400	-	MHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes, f < 12 GHz	-	0.5	1	dB
Vπ RF @50 kHz	$V\pi_{RF \text{ 50 kHz}}$	RF electrodes, @ 1550 nm	-	3.5	4	V
Vπ RF @200 Mb/s PRBS	$V\pi_{RF \text{ 200 Mb/s}}$	RF electrodes, @ 1550 nm	-	1.5	-	V
Vπ DC electrodes	$V\pi_{DC}$	DC electrodes	-	6.5	7	V
RF input impedance	$Z_{in-RF}$	-		High impedance		-
DC input impedance	$Z_{in-DC}$	-	1	-	-	MΩ
50 Ω RF input						

**Optical Characteristics**

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-		Lithium Niobate X-Cut Y-Prop		
Operating wavelength	$\lambda$	-	1530	1550	1580	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC Extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	30	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	-	0.1	-

All specifications given at 25 °C, 1550 nm, unless differently specified.

**Absolute Maximum Ratings**

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias Voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

# MX-LN-05

## 5 GHz Intensity Modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	$S_{21}$	RF electrodes	3	4	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes	-	0.5	1	dB
Electrical return loss, 0-5 GHz	$S_{11}$	RF electrodes	-	-13	-10	dB
Vπ RF @50 kHz	$V\pi_{RF \text{ 50 kHz}}$	RF electrodes, @ 1550 nm	-	3.5	4	V
Vπ DC electrodes	$V\pi_{DC}$	DC electrodes	-	6.5	7	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	1	-	-	$M\Omega$

50  $\Omega$  RF input

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-	Lithium Niobate X-Cut Y-Prop			
Operating wavelength	$\lambda$	-	1530	1550	1580	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC Extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	25	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	-	0.1	-

All specifications given at 25 °C, 1550 nm, unless differently specified.

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias Voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

# MX-LN-10

## 10 GHz Intensity Modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	$S_{21}$	RF electrodes, from 2 GHz	10	12	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes, $f < 12$ GHz	-	0.5	1	dB
Electrical return loss	$S_{11}$	RF electrodes	-	-12	-10	dB
$V\pi$ RF @50 kHz	$V\pi_{RF\ 50\ kHz}$	RF electrodes, @ 1550 nm	-	5.5	6.5	V
$V\pi$ RF @10 Gb/s PRBS	$V\pi_{RF\ 10\ Gb/s}$	RF electrodes, @ 1550 nm	-	6.5	7	V
$V\pi$ DC electrodes	$V\pi_{DC}$	DC electrodes	-	6.5	7	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	-	1	-	$M\Omega$
50 $\Omega$ RF input						

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-		Lithium Niobate X-Cut Y-Prop		
Operating wavelength	$\lambda$	-	1530	1550	1625	nm
Insertion loss	IL	Without connectors	-	3.5	-	dB
Insertion loss (with low IL option)	LIL	Without connectors	-	2.7	3	dB
DC Extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	0	0.1	-

All specifications given at 25 °C, 1550 nm, unless differently specified.

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias Voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

# MX-LN-20

## 20 GHz Intensity Modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	$S_{21}$	RF electrodes, from 2 GHz	20	25	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes, $f < 20$ GHz	-	0.5	1	dB
Electrical return loss	$S_{11}$	RF electrodes	-	-12	-10	dB
$V\pi$ RF @50 kHz	$V\pi_{RF\ 50\ kHz}$	RF electrodes, @ 1550 nm	-	5	5.5	V
$V\pi$ RF @20 Gb/s PRBS	$V\pi_{RF\ 20\ Gb/s}$	RF electrodes, @ 1550 nm	-	5.5	6	V
$V\pi$ DC electrodes	$V\pi_{DC}$	DC electrodes	-	6.5	7	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	-	1	-	$M\Omega$
50 $\Omega$ RF input						

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-		Lithium Niobate X-Cut Y-Prop		
Operating wavelength	$\lambda$	-	1530	1550	1625	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC Extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	0	0.1	-

All specifications given at 25 °C, 1550 nm, unless differently specified.

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias Voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

# MX-LN-40

## 40 GHz Intensity Modulator

### Electrical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Electro-optical bandwidth	$S_{21}$	RF electrodes, from 2 GHz	28	30	-	GHz
Ripple $S_{21}$	$\Delta S_{21}$	RF electrodes, $f < 30$ GHz	-	0.5	1	dB
Electrical return loss	$S_{11}$	RF electrodes	-	-12	-10	dB
Vπ RF @50 kHz	$V\pi_{RF \text{ 50 kHz}}$	RF electrodes, @ 1550 nm	-	5	6	V
Vπ DC electrodes	$V\pi_{DC}$	DC electrodes, @ 1550 nm	-	6.5	7	V
RF input impedance	$Z_{in-RF}$	-	-	50	-	$\Omega$
DC input impedance	$Z_{in-DC}$	-	1	-	-	$M\Omega$

50 Ω RF input

### Optical Characteristics

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Crystal	-	-		Lithium Niobate X-Cut Y-Prop		
Operating wavelength	$\lambda$	-	1530	1550	1625	nm
Insertion loss	IL	Without connectors	-	3.5	4.5	dB
DC Extinction ratio	ER	Measured with narrow source linewidth < 200 MHz	20	22	-	dB
Optical return loss	ORL	-	-40	-45	-	dB
Chirp	$\alpha$	-	-0.1	0	0.1	-

All specifications given at 25 °C, 1550 nm, unless differently specified.

### Absolute Maximum Ratings

Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. These are absolute stress ratings only. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of the data sheet. Exposure to absolute maximum ratings for extended periods can adversely affect device reliability.

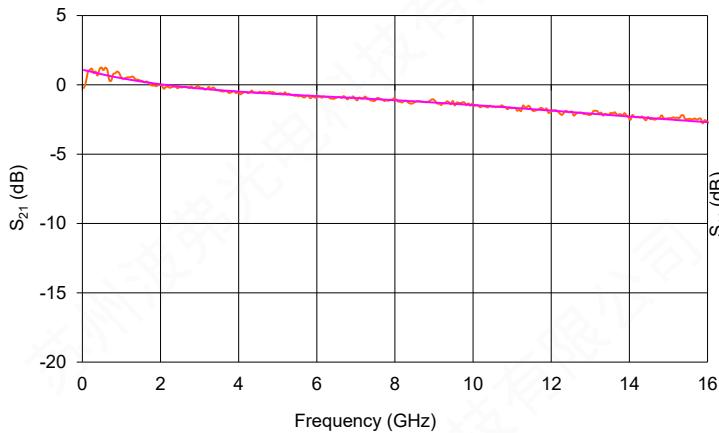
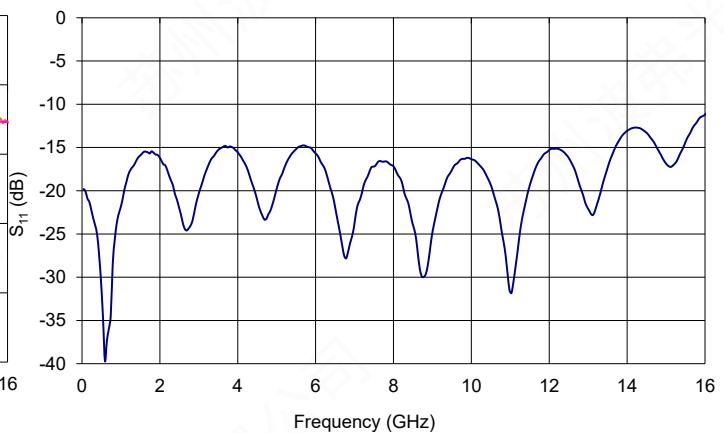
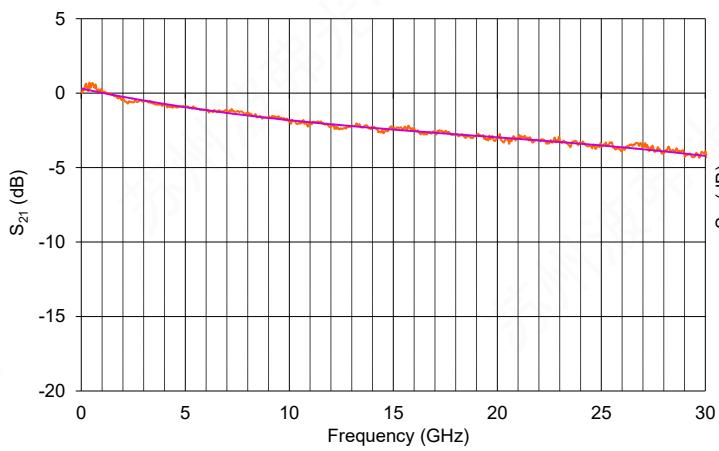
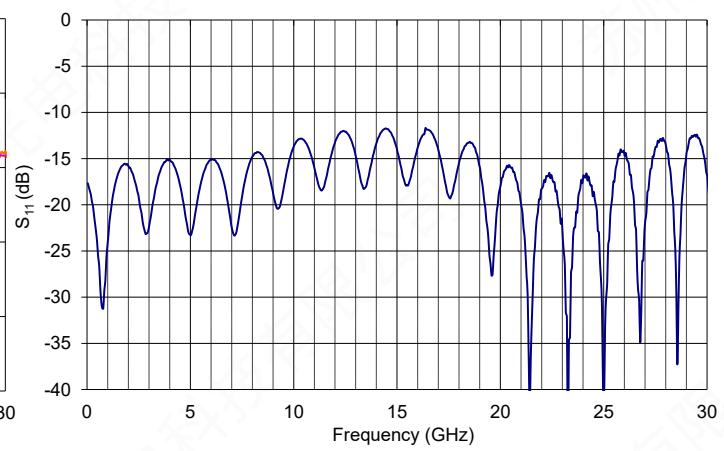
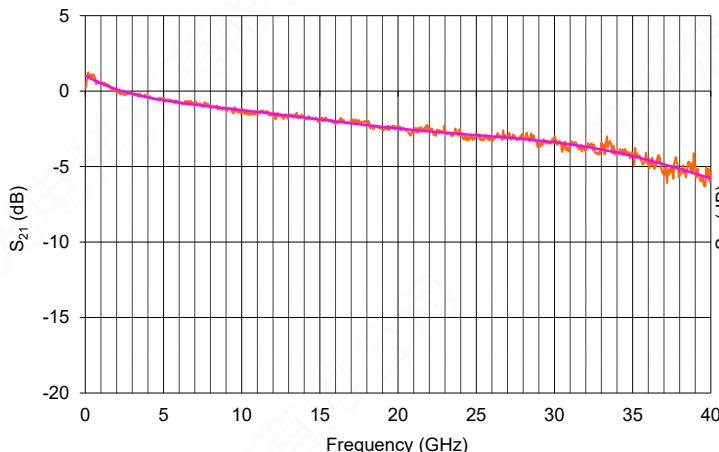
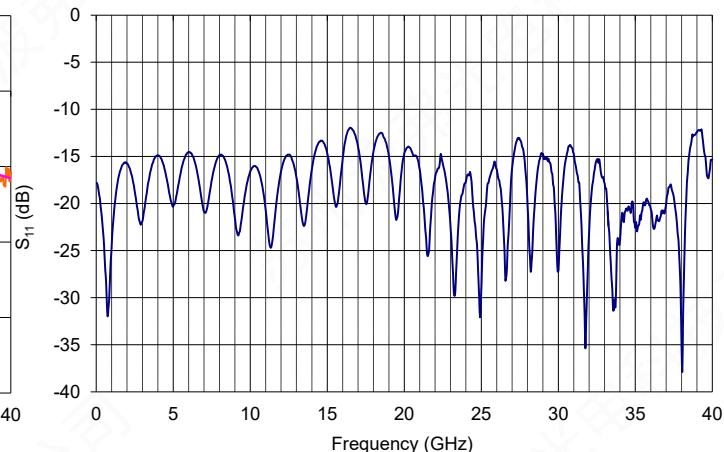
Parameter	Symbol	Min	Max	Unit
RF input power	$EP_{in}$	-	28	dBm
Bias Voltage	$V_{bias}$	-20	+20	V
Optical input power	$OP_{in}$	-	20	dBm
Operating temperature	OT	0	+70	°C
Storage temperature	ST	-40	+85	°C

MODULATOR | **MX-LN SERIES** | 7/9

## **MX-LN-0.1 & 05**

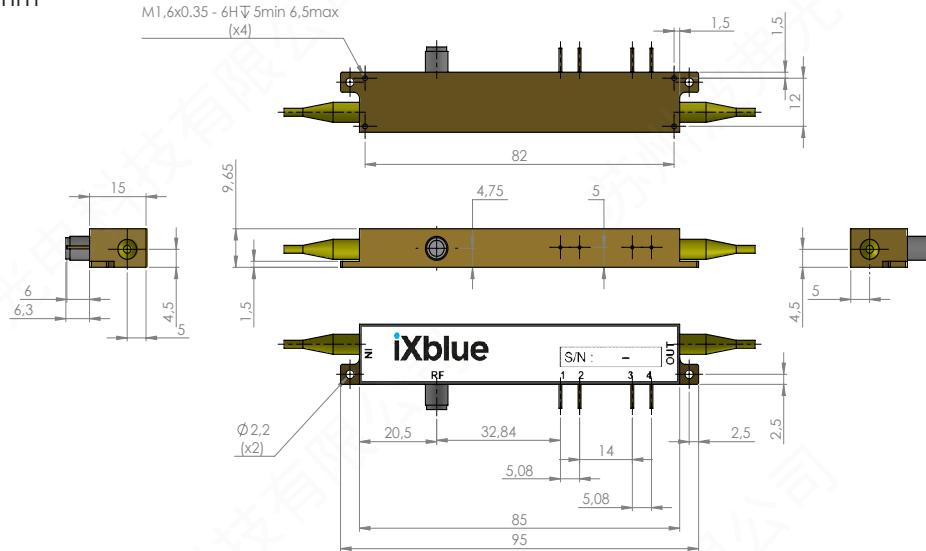
 iXblue

# MX-LN-10, 20 & 40

MX-LN-10 Typical  $S_{21}$  CurveMX-LN-10 Typical  $S_{11}$  CurveMX-LN-20 Typical  $S_{21}$  CurveMX-LN-20 Typical  $S_{11}$  CurveMX-LN-40 Typical  $S_{21}$  CurveMX-LN-40 Typical  $S_{11}$  Curve

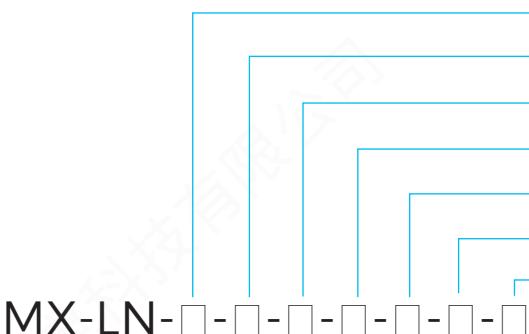
## Mechanical Diagram and Pinout

All measurements in mm



Port	Function	Note
IN	Optical input port	Polarization maintaining fiber Corning PM 15-U25D Length: 1.5 meter, buffer diameter: 900 µm
OUT	Optical output port	Polarization maintaining fiber Corning PM 15-U25D Length: 1.5 meter, buffer diameter: 900 µm
RF	RF input port	MX-LN-0.1, 05, 10: Female K (SMA compatible) MX-LN-20: Female K or 2.4 mm (optional) MX-LN-40: 2.4 mm, female, compatible to mate with V / 1.85 mm connectors (K option)
1	Ground	Pin feed through diameter 1.0 mm
2	DC	Pin feed through diameter 1.0 mm
3, 4	Photodiode cathode, anode	Pin feed through diameter 1.0 mm

## Ordering information



Bandwidth: **0.1** (400 MHz), **05** (4 GHz), **10** (10 GHz),  
**20** (20 GHz), **40** (40 GHz)

Internal photodiode: 00 not integrated PD PD integrated

Input fiber: P Polarization maintaining, S Standard single mode

Output fiber: P Polarization maintaining, S Standard single mode

Input connector: **00** (bare fiber), **FA** (FC/APC)

Output connector: **00** (bare fiber), **FA** (FC/APC)

LIL: Low Insertion Loss option

## About us

ixblue Photonics produces specialty optical fibers and Bragg gratings based fiber optics components and provides optical modulation solutions based on the company lithium niobate ( $\text{LiNbO}_3$ ) modulators and RF electronic modules.

ixblue Photonics serves a wide range of industries: sensing and instruments, defense, telecommunications, space and fiber lasers as well as research laboratories all over the world.

ixblue reserves the right to change, at any time and without notice, the specifications, design, function or form of its products described herein. All statements, specification, technical information related to the products herein are given in good faith and based upon information believed to be reliable and accurate at the moment of printing. However the accuracy and completeness thereof is not guaranteed. No liability is assumed for any inaccuracies and as a result of use of the products. The user must validate all parameters for each application before use and he assumes all risks in connection with the use of the products

**ixblue**